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Facsimile Cover Sheet

Date:	November 26, 2003	First Inventor:	Mohamed N. Darwish
To:	US Patent & Trademark Office Fax: 703-746-9195 Tel: 703-308-1202	Title:	Trench MOSFET Having Implanted Drain-Drift Region And Process For Manufacturing The Same
From:	David E. Steuber Tel: 408/982-8200 ext. 1 Fax: 408/982-8210	Serial No.:	10/650,513
Pages	4 (excluding cover sheet)	Examiner:	Unknown

Enclosed for filing in the above-identified application are the following:
Transmittal Form (1 page);
Filing Receipt (with corrections shown) (1 page); and
Replacement Application Data Sheet (2 pages).

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**TRANSMITTAL
FORM**

(to be used for all correspondence after initial filing)

Total Number Of Pages In This Submission

4

Application Number

10/650,513

Filing Date

8/27/2003

First Named Inventor

Mohamed N. Darwish

Group Art Unit

2812

Examiner Name

Unknown

Attorney Docket No.


SCX010-5D US

ENCLOSURES (check all that apply)☐ Fee Transmittal Form (1 page in duplicate)☐ Fee Attached - Credit Card Payment Form (1 page)☐ Amendment / Reply (## pages)☐ After Final☐ Affidavits/declarations☐ Extension of Time Request (1 page in duplicate)☐ Express Abandonment Request☐ Information Disclosure Statement☐ Certified Copy of Priority Document(s)☐ Response to Missing Parts/ Incomplete Application☐ Response to Missing Parts under 37 CFR 1.52 or 1.53☐ Assignment Papers (for an Application)☐ Drawing(s)☐ Licensing-related Papers☐ Petition☐ Petition to Convert to a Provisional Application☐ Power of Attorney, Revocation of Previous Powers, And Statement Under 37 CFR 3.73(b)☐ Terminal Disclaimer☐ Request for Refund☐ CD, Number of CD(s) _____☐ After Allowance Communication to Group☐ Appeal Communication to Board of Appeals and Interferences☐ Appeal Communication to Group (Appeal Notice, Brief, Reply Brief)☐ Proprietary Information☐ Status Letter☒ Other Enclosure(s) (please identify below):
Marked-up Copy of Filing Receipt showing correction; (1 page); and
Supplemental Application Data Sheet (2 pages).

Remarks

SIGNATURE OF APPLICANT, ATTORNEY OR AGENTFirm
or
Individual NameOmkar K. Suryadevara (Reg. No. 36,320)
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Date

November 26, 2003

CERTIFICATE OF FACSIMILE TRANSMISSION

I hereby certify that this correspondence is being facsimile transmitted to the U.S. Patent and Trademark Office to the fax number 703-746-9795 on November 26, 2003.

Attorney for Applicant(s)

Date of Signature



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CONFIRMATION NO. 5781

FILING RECEIPT

1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22 23 24 25 26 27 28 29 30 31 32 33 34 35 36 37 38 39 40 41 42 43 44 45 46 47 48 49 50 51 52 53 54 55 56 57 58 59 60 61 62 63 64 65 66 67 68 69 70 71 72 73 74 75 76 77 78 79 80 81 82 83 84 85 86 87 88 89 90 91 92 93 94 95 96 97 98 99 100
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Applicant(s)

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Assignment For Published Patent Application

Siliconix Incorporated, Campbell, CA;

Santa Clara

Domestic Priority data as claimed by applicant

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Foreign Applications

If Required, Foreign Filing License Granted: 11/19/2003

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Early Publication Request: No

Title

Trench MOSFET having implanted drain-drift region and process for manufacturing the same